MBR735 – MBR7150

Taiwan Semiconductor

7.5A, 35V - 150V Schottky Barrier Rectifier

FEATURES

TAIWAN

• AEC-Q101 qualified available

EMICONDUCTOR

- Low power loss, high efficiency
- Guard ring for overvoltage protection
- High surge current capability
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- DC to DC converters

MECHANICAL DATA

- Case: TO-220AC
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Mounting torque: 0.56 N·m maximum
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.85g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
I _F	7.5	А
V _{RRM}	35 - 150	V
I _{FSM}	150	А
T _{J MAX}	150	°C
Package	TO-220	DAC
Configuration	Single	die







		MBR	MBR	MBR	MBR	MBR	MBR	MBR	
PARAMETER	SYMBOL	735	745	750	760	790	7100	7150	UNIT
Marking code on the device		MBR 735	MBR 745	MBR 750	MBR 760	MBR 790	MBR 7100	MBR 7150	
Repetitive peak reverse voltage	V _{RRM}	35	45	50	60	90	100	150	V
Reverse voltage, total rms value	V _{R(RMS)}	24	31	35	42	63	70	105	V
Forward current	I _F				7.5				Α
Surge peak forward current 8.3ms single half sine wave superimposed on rated load	I _{FSM}				150				A
Peak repetitive forward current (Rated V_R , Square Wave, 20KHz)	I _{FRM}	15				А			
Peak repetitive reverse surge current ⁽¹⁾	I _{RRM}		1			0.5			А
Voltage rate of change (Rated V_R)	dV/dt				10,000				V/µs
Junction temperature	TJ			-5	55 to +15	50			°C
Storage temperature	T _{STG}			-5	55 to +17	' 5			°C

Notes:

1. $tp = 2.0 \mu s$, 1.0KHz



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-ambient resistance	R _{eja}	15	°C/W
Junction-to-case resistance	R _{eJC}	5	°C/W

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
_	MBR735 MBR745	I _F = 7.5A, T _J = 25°C		-	-	V
	MBR750 MBR760			-	0.75	V
	MBR790 MBR7100			-	0.92	V
	MBR7150			-	0.95	V
	MBR735 MBR745			-	0.84	V
	MBR750 MBR760	I _F = 15A, T _J = 25°C	-	-	-	V
	MBR790 MBR7100	F = 10, (, 1) = 20 0		-	-	V
Forward voltage ⁽¹⁾	MBR7150		V	-	-	V
Forward voltage	MBR735 MBR745	. I _F = 7.5A, T _J = 125°C	V _F	-	0.57	V
	MBR750 MBR760			-	0.65	V
	MBR790 MBR7100			-	0.82	V
	MBR7150			-	0.92	V
	MBR735 MBR745	. I _F = 15A, T _J = 125°C		-	0.72	V
	MBR750			-	_	V
	MBR760 MBR790			-	_	V
	MBR7100 MBR7150			-	_	V
Reverse current @ rated V _R ⁽²⁾	MBR735 MBR745 MBR750 MBR760 MBR790 MBR7100 MBR7150	T _J = 25°C		-	100	μA
	MBR735 MBR745		I _R	-	15	mA
	MBR750 MBR760	T」= 125°C		-	10	mA
	MBR790 MBR7100 MBR7150	1, 1, - 120 0		-	5	mA

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms



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ORDERING INFORMATION

ORDERING CODE ⁽¹⁾⁽²⁾	PACKAGE	PACKING
MBR7x	TO-220AC	50 / Tube
MBR7xH	TO-220AC	50 / Tube

Notes:

1. "x" defines voltage from 35V(MBR735) to 150V(MBR7150)

2. "H" means AEC-Q101 qualified



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

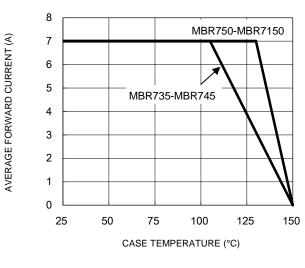
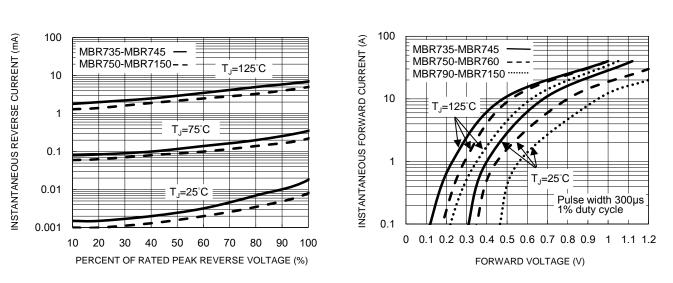


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics



1000

100

10

0.1

CAPACITANCE (pF)

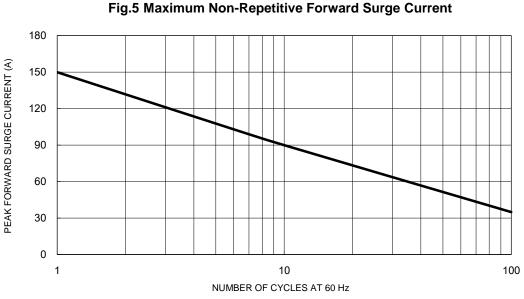


Fig.2 Typical Junction Capacitance

MBR750-MBR760

+++

1

f=1.0MHz

Vsig=50mVp-p

MBR790-MBR7150

10

REVERSE VOLTAGE (V)

Fig.4 Typical Forward Characteristics

100

MBR735-MBR745



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

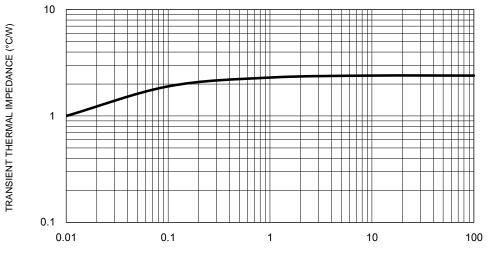


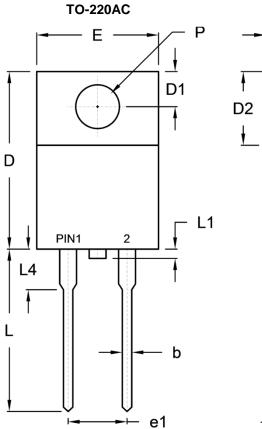
Fig.6 Typical Transient Thermal Impedance

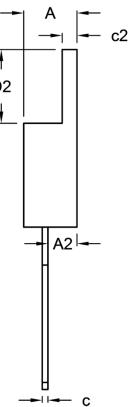
PULSE DURATION (s)

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PACKAGE OUTLINE DIMENSIONS





DIM.	Unit (mm)		Unit	(inch)
	Min.	Max.	Min.	Max.
A	4.42	4.76	0.174	0.187
A2	2.20	2.80	0.087	0.110
b	0.68	0.94	0.027	0.037
с	0.35	0.64	0.014	0.025
c2	1.14	1.40	0.045	0.055
D	14.60	16.00	0.575	0.630
D1	2.62	3.44	0.103	0.135
D2	5.84	6.86	0.230	0.270
Е	-	10.50	-	0.413
e1	4.95	5.20	0.195	0.205
L	13.19	14.79	0.519	0.582
L1	0.00	1.60	0.000	0.063
L4	2.80	4.20	0.110	0.165
Р	3.54	4.00	0.139	0.157

MARKING DIAGRAM



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



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